

#### **60V NPN MEDIUM POWER TRANSISTOR IN SOT89**

#### **Features**

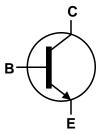
- BV<sub>CEO</sub> > 60V
- Ic = 1A Continuous Collector Current
- I<sub>CM</sub> = 2A Peak Pulse Current
- $R_{CE(sat)} = 195m\Omega$  for a Low Equivalent On-Resistance
- hFE Characterized up to 2A for High Current Gain Hold-Up
- Complementary PNP Type: FCX591
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

#### **Mechanical Data**

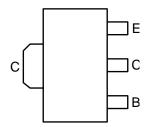
- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound;
   UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.055 grams (Approximate)







**Equivalent Circuit** 



Top View Pin-Out

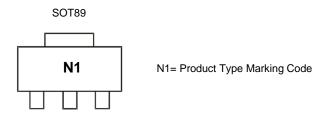
#### Ordering Information (Notes 4 and 5)

| Product   | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-----------|------------|---------|--------------------|-----------------|-------------------|
| FCX491TA  | AEC-Q101   | N1      | 7                  | 12mm            | 1,000             |
| FCX491QTA | Automotive | N1      | 7                  | 12mm            | 1,000             |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**







### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic               | Symbol           | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage       | V <sub>CBO</sub> | 80    | V    |
| Collector-Emitter Voltage    | V <sub>CEO</sub> | 60    | V    |
| Emitter-Base Voltage         | $V_{EBO}$        | 7     | V    |
| Continuous Collector Current | Ic               | 1     | Α    |
| Peak Pulse Current           | I <sub>CM</sub>  | 2     | Α    |

### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic                              | Symbol                            | Value             | Unit |      |  |
|---|-----------------------------------|-------------------|------|------|--|
|   | (Note 6)                          |                   | 1    |      |  |
| Power Dissipation                           | (Note 7)                          | $P_{D}$           | 1.5  | W    |  |
|   | (Note 8)                          |                   | 2.0  |      |  |
|   | (Note 6)                          |                   | 125  |      |  |
| Thermal Resistance, Junction to Ambient Air | (Note 7)                          | $R_{\theta JA}$   | 83   |      |  |
|   | (Note 8)                          |                   | 60   | °C/W |  |
| Thermal Resistance, Junction to Lead        | (Note 9)                          | $R_{	heta JL}$    | 22   |      |  |
| Thermal Resistance, Junction to Case        | (Note 10)                         | R <sub>0</sub> JC | 16   |      |  |
| Operating and Storage Temperature Range     | T <sub>J</sub> , T <sub>STG</sub> | -65 to +150       | °C   |      |  |

#### ESD Ratings (Note 11)

| Characteristic                             | Symbol  | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V    | 3A          |
| Electrostatic Discharge - Machine Model    | ESD MM  | 400   | V    | С           |

Notes:

- 6. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.

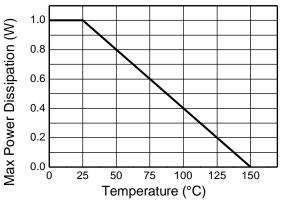
  8. Same as Note 5, except the device is mounted on 50mm x 50mm 1oz copper.
- 9. Thermal resistance from junction to solder-point (on the exposed collector pad).

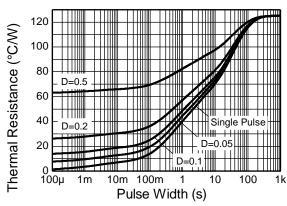
  10. Thermal resistance from junction to the top of the case.

  11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



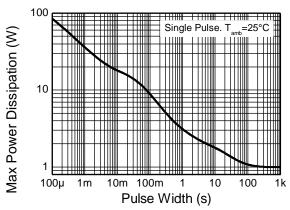
### **Thermal Characteristics and Derating Information**



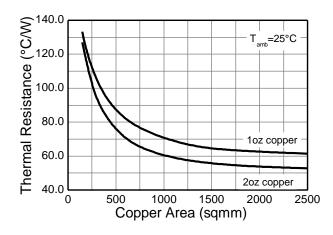


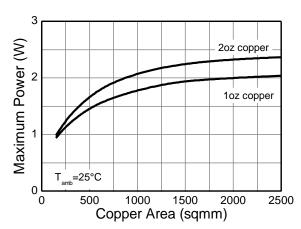
#### **Derating Curve**

**Transient Thermal Impedance** 



**Pulse Power Dissipation** 









### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

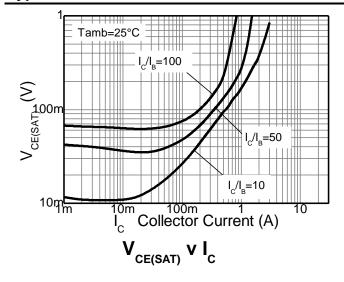
| Characteristic                                 | Symbol               | Min                    | Тур                     | Max        | Unit | Test Condition  |
|--|----------------------|------------------------|-------------------------|------------|------|---|
| Collector-Base Breakdown Voltage               | $BV_CBO$             | 80                     | _                       | _          | V    | $I_C = 100\mu A$  |
| Collector-Emitter Breakdown Voltage (Note 12)  | $BV_CEO$             | 60                     | _                       | _          | V    | $I_C = 10mA$  |
| Emitter-Base Breakdown Voltage                 | $BV_{EBO}$           | 7                      | 8.1                     | _          | V    | $I_E = 100\mu A$  |
| Collector-Base Cut-Off Current                 | I <sub>CBO</sub>     | _                      | <1                      | 100        | nA   | $V_{CB} = 60V$  |
| Collector Cut-Off Current                      | I <sub>CES</sub>     | _                      | <1                      | 100        | nA   | V <sub>CES</sub> = 60V  |
| Emitter Cut-Off Current                        | I <sub>EBO</sub>     | _                      | <1                      | 100        | nA   | $V_{EB} = 5.6V$   |
| Collector-Emitter Saturation Voltage (Note 12) | V <sub>CE(sat)</sub> | _                      | 100<br>160              | 250<br>500 | mV   | $I_C = 500$ mA, $I_B = 50$ mA<br>$I_C = 1$ A, $I_B = 100$ mA  |
| Base-Emitter Saturation Voltage (Note 12)      | V <sub>BE(sat)</sub> | _                      | 965                     | 1100       | mV   | $I_C = 1A$ , $I_B = 100mA$  |
| Base-Emitter Turn-On Voltage (Note 12)         | V <sub>BE(on)</sub>  | _                      | 830                     | 1000       | mV   | $I_C = 1A, V_{CE} = 5V$   |
| DC Current Gain (Note 12)                      | h <sub>FE</sub>      | 100<br>100<br>80<br>30 | 140<br>150<br>120<br>40 | 300        | _    | $I_{C} = 1$ mA, $V_{CE} = 5$ V<br>$I_{C} = 500$ mA, $V_{CE} = 5$ V<br>$I_{C} = 1$ A, $V_{CE} = 5$ 0V<br>$I_{C} = 2$ A, $V_{CE} = 5$ V |
| Transitional Frequency                         | f⊤                   | 150                    | _                       | _          | MHz  | I <sub>C</sub> = 50mA, V <sub>CE</sub> = 10V<br>f=100MHz  |
| Output Capacitance                             | C <sub>obo</sub>     | _                      | _                       | 10         | pF   | V <sub>CB</sub> = 10V, f=1MHz   |
| Turn-On Time                                   | t <sub>on</sub>      | _                      | 49                      | _          | ns   |   |
| Delay Time                                     | t <sub>d</sub>       | _                      | 18                      | _          | ns   | ]   |
| Rise Time                                      | t <sub>r</sub>       | _                      | 31                      | _          | ns   | $V_{CC} = 10V$  |
| Turn-Off Time                                  | t <sub>off</sub>     | _                      | 476                     | _          | ns   | $I_{CC} = 0.5A$<br>$I_{B1} = -I_{B2} = 25mA$  |
| Storage Time                                   | ts                   |                        | 414                     |            | ns   | 101 - 182 - 23HIV   |
| Fall Time                                      | t <sub>f</sub>       |                        | 62                      |            | ns   |   |

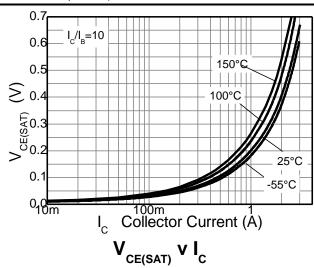
Note:

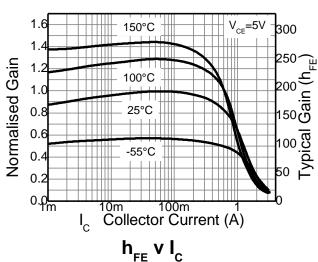
12. Measured under pulsed conditions. Pulse width  $\leqslant$  300µs. Duty cycle  $\leqslant$  2%

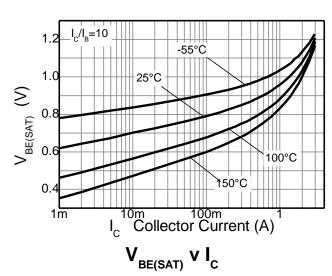


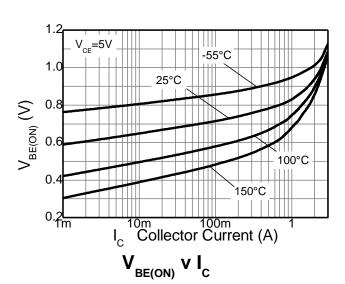
### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)







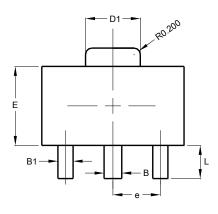


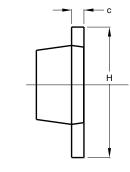


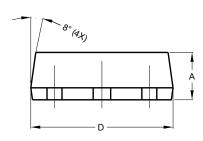


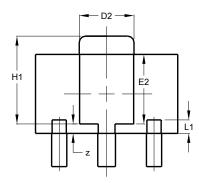
# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.





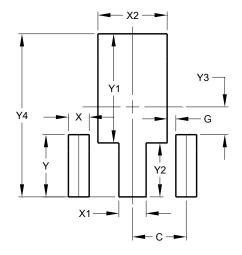




| SOT89                |       |       |       |  |  |
|----------------------|-------|-------|-------|--|--|
| Dim                  | Min   | Max   | Тур   |  |  |
| Α                    | 1.40  | 1.60  | 1.50  |  |  |
| В                    | 0.50  | 0.62  | 0.56  |  |  |
| B1                   | 0.42  | 0.54  | 0.48  |  |  |
| С                    | 0.35  | 0.43  | 0.38  |  |  |
| D                    | 4.40  | 4.60  | 4.50  |  |  |
| D1                   | 1.62  | 1.83  | 1.733 |  |  |
| D2                   | 1.61  | 1.81  | 1.71  |  |  |
| Е                    | 2.40  | 2.60  | 2.50  |  |  |
| E2                   | 2.05  | 2.35  | 2.20  |  |  |
| е                    | 1     | -     | 1.50  |  |  |
| Н                    | 3.95  | 4.25  | 4.10  |  |  |
| H1                   | 2.63  | 2.93  | 2.78  |  |  |
| L                    | 0.90  | 1.20  | 1.05  |  |  |
| L1                   | 0.327 | 0.527 | 0.427 |  |  |
| Z                    | 0.20  | 0.40  | 0.30  |  |  |
| All Dimensions in mm |       |       |       |  |  |

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value<br>(in mm) |  |  |
|------------|------------------|--|--|
| С          | 1.500            |  |  |
| G          | 0.244            |  |  |
| X          | 0.580            |  |  |
| X1         | 0.760            |  |  |
| X2         | 1.933            |  |  |
| Υ          | 1.730            |  |  |
| Y1         | 3.030            |  |  |
| Y2         | 1.500            |  |  |
| Y3         | 0.770            |  |  |
| Y4         | 4.530            |  |  |





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